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Vishay General Semiconductor

Dual Low-Voltage TMBS[®] (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.36$ V at $I_F = 2.5$ A





LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 5 A			
V _{RRM}	60 V			
I _{FSM}	100 A			
V_F at $I_F = 5 \text{ A} (T_J = 125 \text{ °C})$	0.48 V			
T _J max.	150 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Common cathode			

FEATURES

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
 Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

MECHANICAL DATA

Case: SMPD (TO-263AC) Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test **Polarity:** as marked

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	V10DL63C	UNIT		
Device marking code		V10DL63C			
Maximum repetitive peak reverse voltage	V _{RRM}	60	V		
Maximum average forward rectified currentper dev	ICE IF(AV) (1)	10	А		
(fig. 1) per dioc	de ^{IF(AV)}	5	~		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	100	А		
Operating junction temperature range	T _J ⁽²⁾	-40 to +150	℃		
Storage temperature range	T _{STG}	-55 to +150	U		

Notes

⁽¹⁾ Mounted on infinite heatsink

 $^{(2)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: dP_D/dT_J < 1/R_{0JA}

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V10DL63C







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ELECTRICAL CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 2.5 A	T 05 %0		0.45	-	
	$T_J = 25 \text{ °C}$	V _F (1)	0.52	0.60	v	
	I _F = 2.5 A	- T _J = 125 °C	VF	0.36	-	V
	I _F = 5 A			0.48	0.55	
Reverse current at rated V_R per diode	V _R = 60 V	T _J = 25 °C	I _R ⁽²⁾	-	0.08	mA
		T _J = 125 °C		4	9	
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	740	-	pF

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 5 ms

THERMAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)				
PARAMETER	SYMBOL	V10DL63C	UNIT	
Typical thermal resistance per device	R _{0JC} ⁽¹⁾	2.5	°C/W	
	R _{0JA} (2)(3)	58	C/W	

Notes

⁽¹⁾ Mounted on infinite heatsink

 $^{(2)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$ - junction-to-ambient

⁽³⁾ Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V10DL63C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel		
V10DL63CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

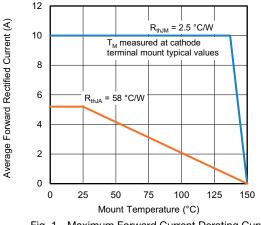


Fig. 1 - Maximum Forward Current Derating Curve

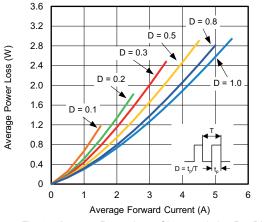


Fig. 2 - Average Power Loss Characteristics Per Diode

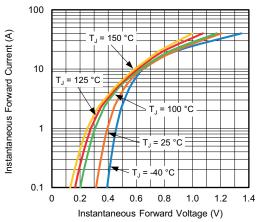


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

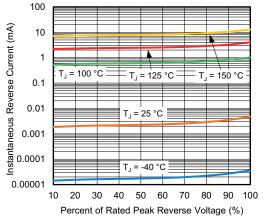
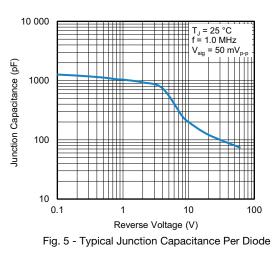
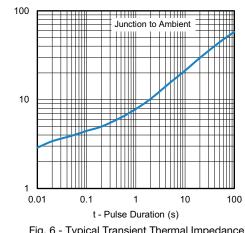


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode







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Transient Thermal Impedance (°C/W)

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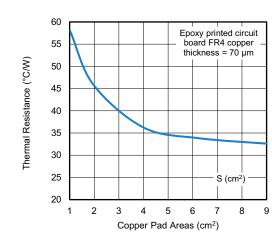
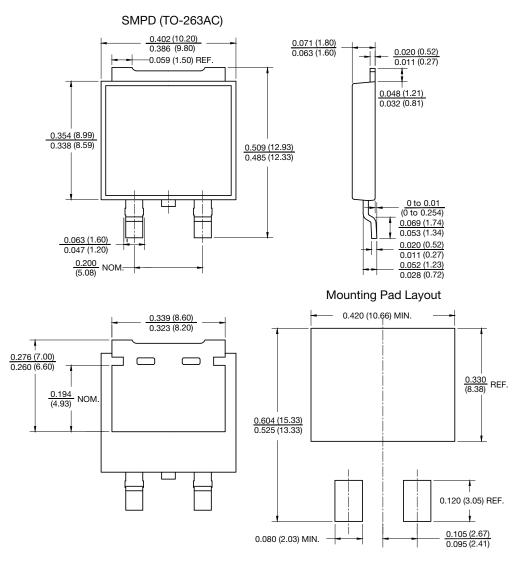


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

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